

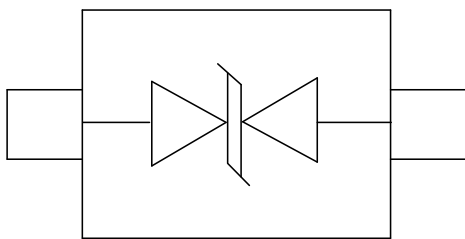
Description

The DC3321D9 is a 3.3V bi-directional ESD protection diode, utilizing leading monolithic silicon technology to provide fast response time and ultra low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The DC3321D9 complies with the IEC 61000-4-2 (ESD) standard with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into an ultra-small lead-free SOD-923 package. The small size and high ESD surge protection make DC3321D9 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Mechanical Characteristics

- ◆ Package: SOD-923
- ◆ Case Material: "Green" Molding Compound.
- ◆ Moisture Sensitivity: Level 3 per J-STD-020
- ◆ Terminal Connections: See Diagram Below
- ◆ Marking Information: See Below

Dimensions and Pin Configuration



Circuit and Pin Schematic

Features

- ◆ Protects one data line
- ◆ Ultra low leakage: nA level
- ◆ Operating voltage: 3.3V
- ◆ Ultra low clamping voltage
- ◆ Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30\text{kV}$
 - Contact discharge: $\pm 30\text{kV}$
 - IEC61000-4-5 (Lightning) 8A (8/20 μs)
- ◆ RoHS Compliant

Applications

- ◆ Cellular Handsets and Accessories
- ◆ Personal Digital Assistants
- ◆ Notebooks and Handhelds
- ◆ Portable Instrumentation
- ◆ Digital Cameras
- ◆ Peripherals
- ◆ Audio Players
- ◆ Keypads, Side Keys, LCD Displays

Marking Information



Ordering Information

Part Number	Marking	Packaging	Reel Size
DC3321D9	33	8000/Tape & Reel	7 inch

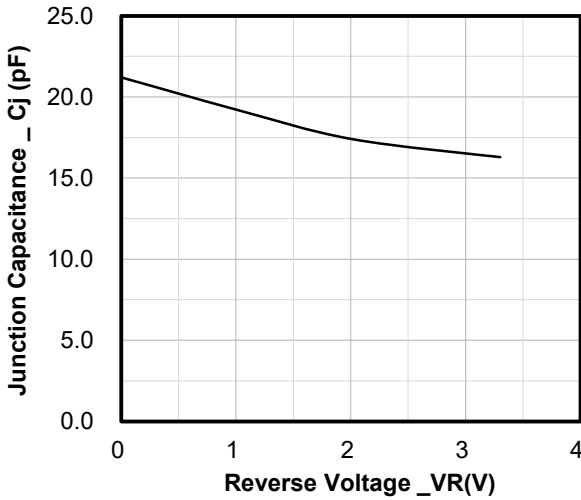
Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power(8/20 μs)	Ppk	100	W
Peak Pulse Current(8/20 μs)	I _{PP}	10	A
ESD per IEC 61000-4-2 (Air)	V _{ESD}	± 30	kV
ESD per IEC 61000-4-2 (Contact)		± 30	
Operating Temperature Range	T _J	-55 to +125	$^{\circ}\text{C}$
Storage Temperature Range	T _{stg}	-55 to +150	$^{\circ}\text{C}$

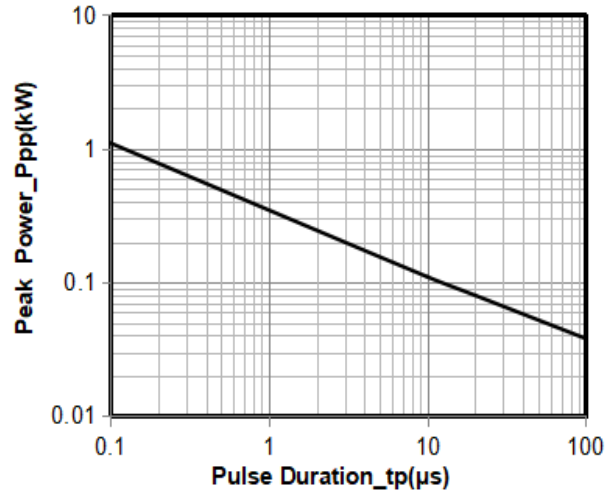
Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			3.3	V	
Snap-Back Voltage	V _{br}	4.0		6.0	V	I _T = 1mA
Reverse Leakage Current	I _R			200	nA	V _{RWM} = 3.3V
Clamping Voltage	V _C		5	6	V	I _{PP} = 1A (8 x 20 μs pulse)
Clamping Voltage	V _C		6.5	8	V	I _{PP} = 5A (8 x 20 μs pulse)
Clamping Voltage	V _C		8.5	10	V	I _{PP} = 10A (8 x 20 μs pulse)
Junction Capacitance	C _J		20	25	pF	V _R = 0V, f = 1MHz

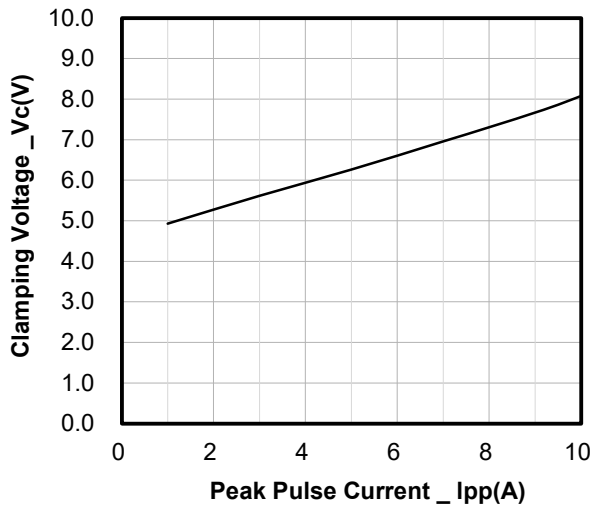
Typical Performance Characteristics (TA=25°C unless otherwise Specified)



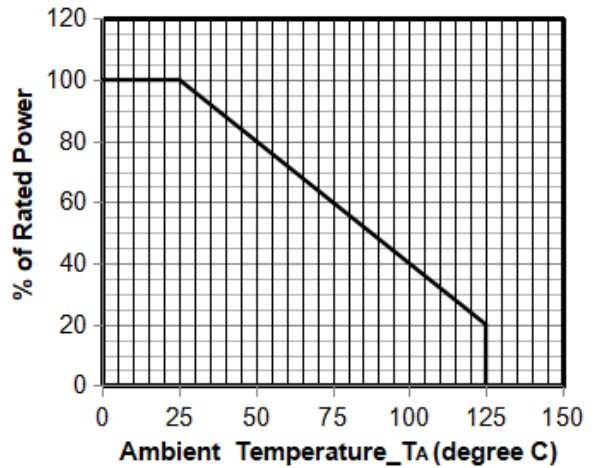
Junction Capacitance vs. Reverse Voltage



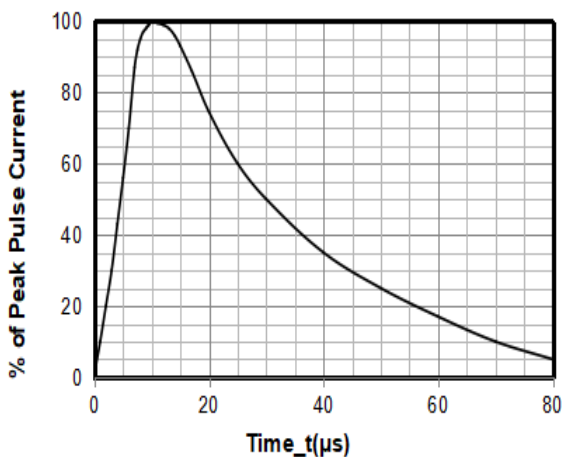
Peak Pulse Power vs. Pulse Time



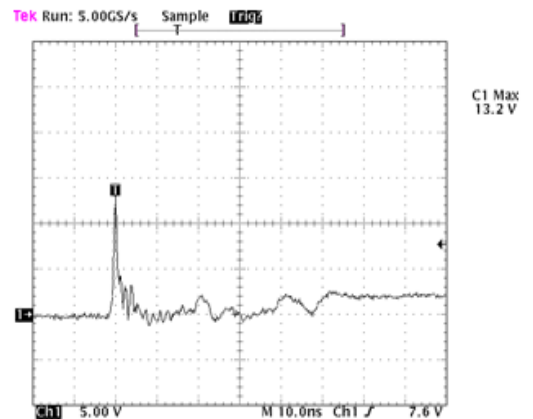
Clamping Voltage vs. Peak Pulse Current



Power Derating Curve



8 X 20μs Pulse Waveform

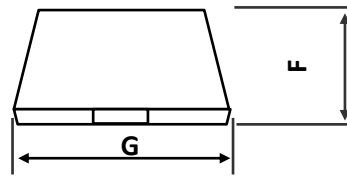
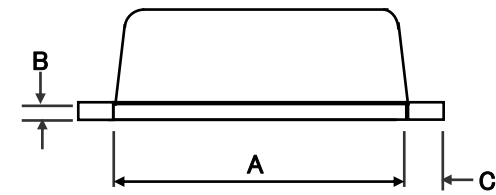


Note: Data is taken with a 10x attenuator

ESD Clamping Voltage

8 kV Contact per IEC61000-4-2

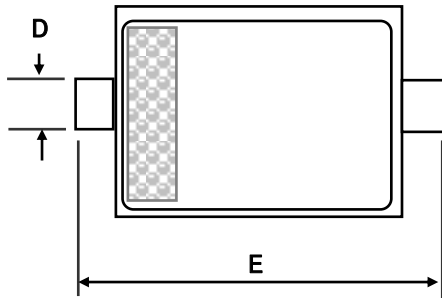
SOD-923 Package Outline Drawing



Dimensions

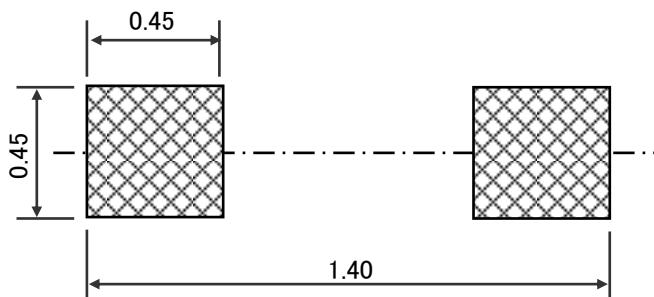
Unit	A	B	C	D	E	F	G
Max.	0.90	0.20	0.15	0.30	1.10	0.45	0.65
Min.	0.70	0.05	0.05	0.15	0.90	0.39	0.55

Unit: mm



SOD923 * Package Outline

Suggested Land Pattern



Contact Information

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